

# 2SC2610

Silicon NPN Triple Diffused

REJ03G0700-0200  
(Previous ADE-208-1068)

Rev.2.00

Aug.10.2005

## Application

- High voltage amplifier
- TV Video output

## Outline

RENESAS Package code: PRSS0003DC-A  
(Package name: TO-92 Mod)

1. Emitter
2. Collector
3. Base

## Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Ratings	Unit
Collector to base voltage	V <sub>CBO</sub>	300	V
Collector to emitter voltage	V <sub>CEO</sub>	300	V
Emitter to base voltage	V <sub>EBO</sub>	5	V
Collector current	I <sub>C</sub>	100	mA
Collector power dissipation	P <sub>C</sub>	800	mW
Junction temperature	T <sub>J</sub>	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C

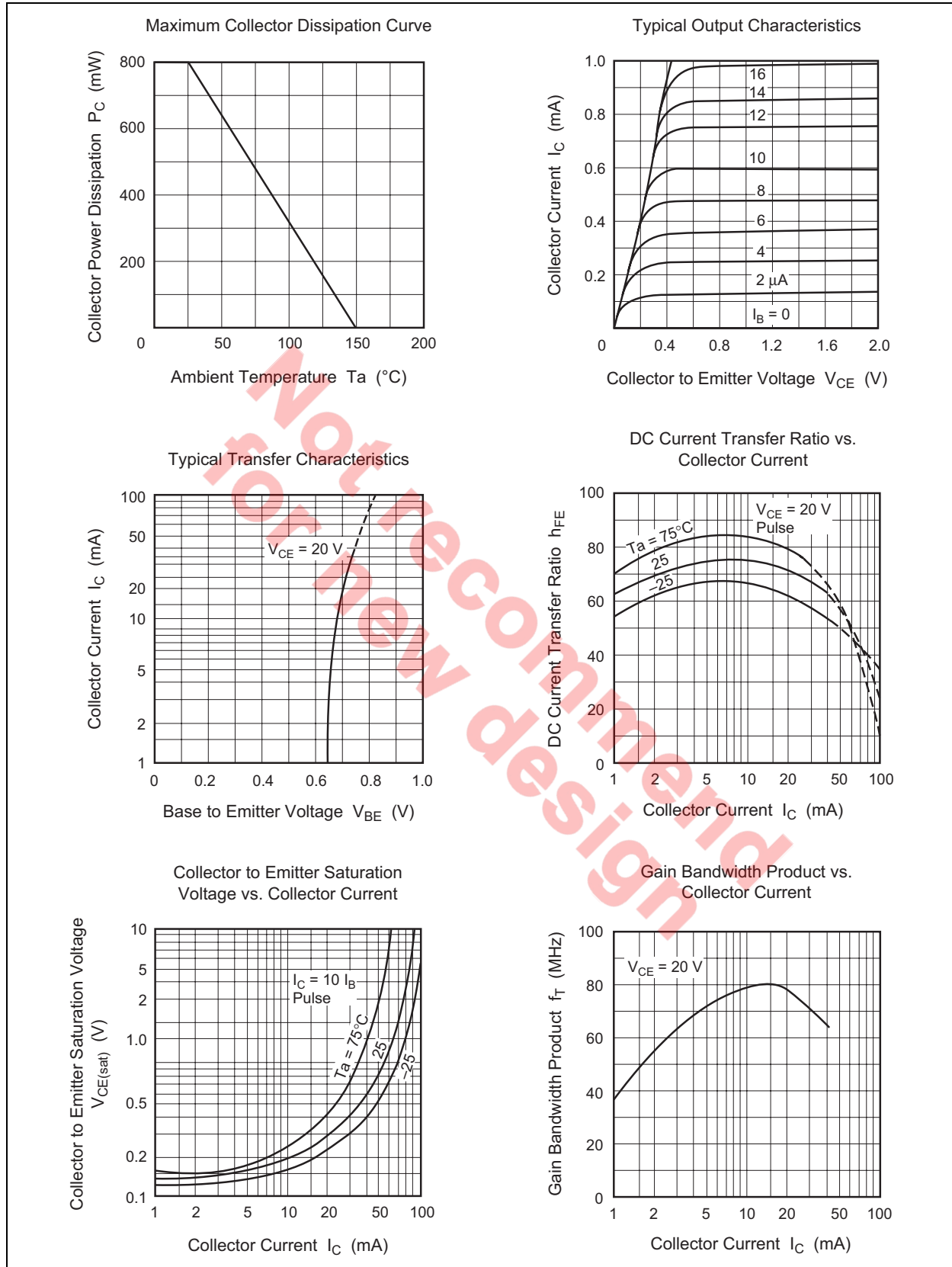
## Electrical Characteristics

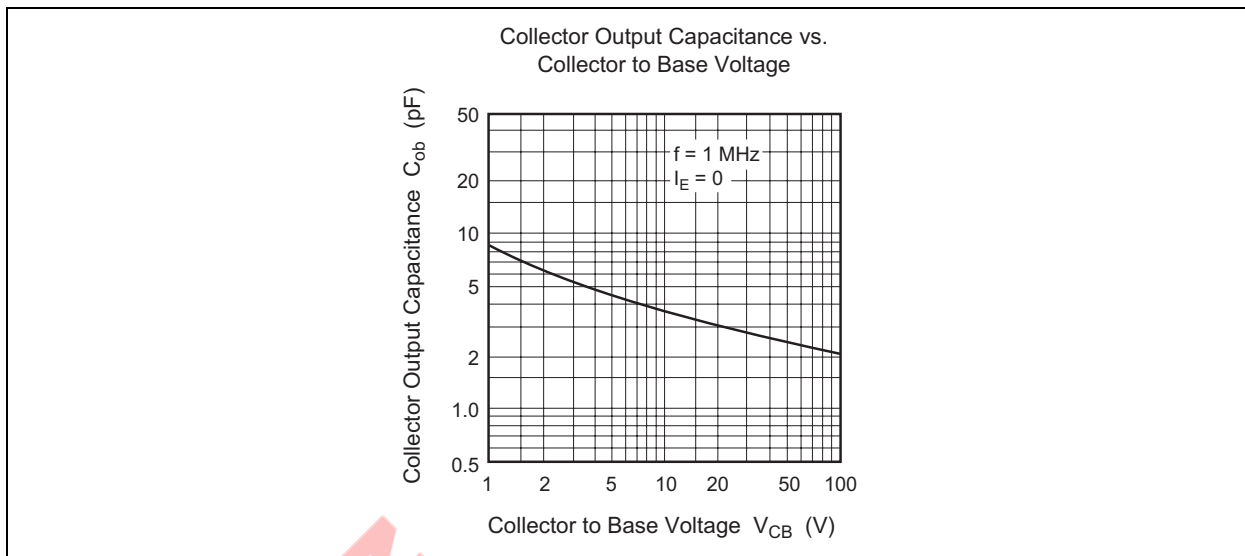
(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	300	—	—	V	$I_C = 10 \mu A, I_E = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	300	—	—	V	$I_C = 1 \text{ mA}, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	—	—	V	$I_E = 10 \mu A, I_C = 0$
Collector cutoff current	$I_{CEO}$	—	—	1.0	$\mu A$	$V_{CE} = 250 \text{ V}, R_{BE} = \infty$
DC current transfer ratio	$h_{FE}$	30	—	200		$V_{CE} = 20 \text{ V}, I_C = 20 \text{ mA}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	—	1.5	V	$I_C = 20 \text{ mA}, I_B = 2 \text{ mA}$
Gain bandwidth product	$f_T$	50	80	—	MHz	$V_{CE} = 20 \text{ V}, I_C = 20 \text{ mA}$
Collector output capacitance	Cob	—	—	4.0	pF	$V_{CB} = 20 \text{ V}, I_E = 0, f = 1 \text{ MHz}$

Not recommend  
for new design

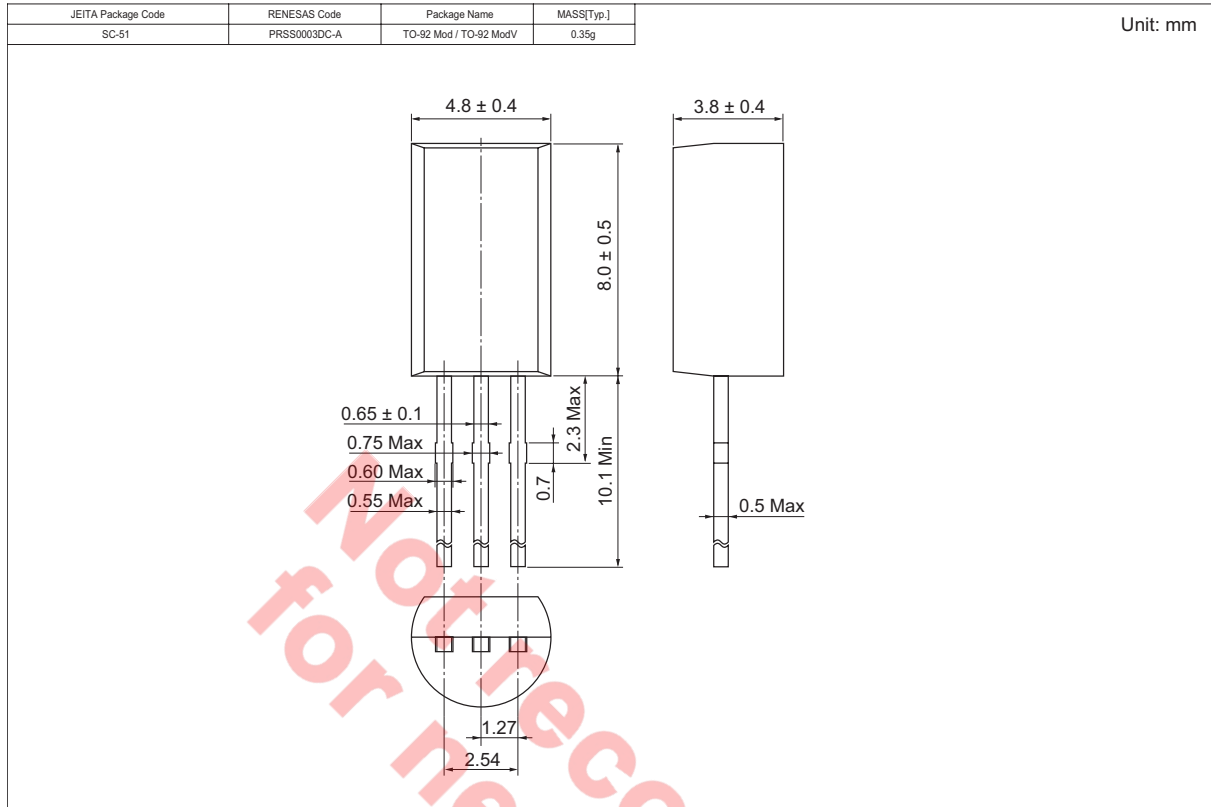
Main Characteristics





Not recommend  
for new design

## Package Dimensions



## Ordering Information

Part Name	Quantity	Shipping Container
2SC2610TZ-E	2500	Hold Box, Radial Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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